## Fast & Soft Recovery Diode

# **DBA100UA60**

### IF(AV)= 2x50A, VRRM=600V, trr=110ns

SanRex Fast & Soft Recovery Diode Module **DBA100UA60** is designed for applications requiring fast switching and soft recovery wave shape to reduce or eliminate the need for snubber components in the circuit. The modules are isolated for easy mounting with other components or a common heatsink.

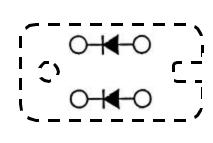
#### Features

- \* Very Fast Reverse Recovery Time
- \* Soft Recovery Characteristics
- \* Low Forward Voltage Drop
- \* Compact isolated SOT-227 package

#### **Typical Applications**

- \* Welding and Plasma Cutting Machines
- \* DC chopper
- \* Rectifier in Switch Mode Power Supplies (SMPS)
- \* Uninterruptible Power Supplies (UPS)
- \* Free Wheeling Diode in converters and motor control circuits





Internal schematic diagram

<	Maximum	Ratings >
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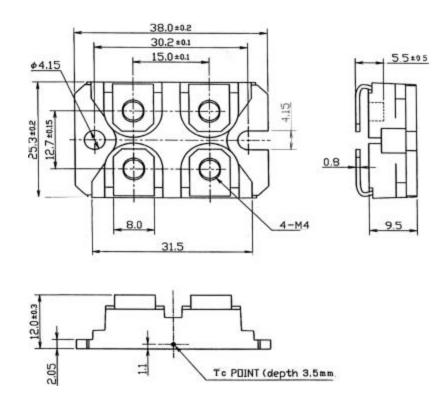
#### $T_j = 25^{\circ}C$ (unless otherwise noted) per diode

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Symbol		Item	Conditions	Ratings	Unit
V <sub>RRM</sub>	Repetitive Peak Reverse			600	V
	Voltage				
V <sub>R(DC)</sub>	Reverse D.	.C. Voltage		480	V
I <sub>F(AV)</sub>	Average Forward Current		D.C., T <sub>C</sub> = 92°C	50	А
I <sub>FSM</sub>	Surge Forward Current		1/2 cycle, 60Hz, Peak value, non-repetitive	490	А
l²t	I <sup>2</sup> t (for fusing)		Value for one cycle surge current	1000	A <sup>2</sup> s
Tj	Junction Temperature			-40 to +150	°C
Tstg	Storage Temperature			-40 to +125	°C
V <sub>ISO</sub>	Isolation Voltage (R.M.S.)		A.C. 1 minute	2500	V
	Mounting	Mounting M4	Recommended 1.0-1.4	1.5	N∙m
	Torque	Terminal M4	Recommended 1.0-1.4	1.5	
	Mass		Typical Value	30	g

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< Electric	cal Characteristics >	Tj= 25 <sup>°</sup> C (	آj= 25 °C (unless otherwise noted) per diode				
Symbol	Item	Conditions	Ratings		Unit		
			Min.	Тур.	Max.		
I <sub>RRM</sub>	Repetitive Peak Reverse Current	V <sub>R</sub> = V <sub>RRM,</sub> Tj= 150°C			100	mA	
V <sub>FM</sub>	Forward Voltage Drop	I <sub>F</sub> = 50A, Inst. measurement		1.25	1.35	V	
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 50A, V <sub>R</sub> =300V, -di / dt = 100A/Fs		110	200	n s	
Rth(j-c)	Thermal Resistance	Junction to case			0.85	°C/W	



\* Dimensions in millimeters